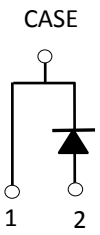
Description

United Silicon Carbide, Inc. offers the xR series of high performance SiC Schottky diodes. With zero reverse recovery charge and 175°C maximum junction temperature, USCi's diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.



Part Number	Package	Marking
UJD06504TS	TO-220-2L	UJD06504TS

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175°C maximum operating junction temperature
- Extremely fast switching not dependent on temperature
- Essentially no reverse or forward recovery
- Enhanced surge capability
- RoHS compliant

Typical Applications

- Power converters
- Industrial motor drives
- Switching-mode power supplies
- Power factor correction modules

Maximum Ratings

Parameter	Symbol	Test Conditions	Value	Units
DC blocking voltage	V_R		650	V
Repetitive peak reverse voltage, T_j=25°C	V_{RRM}		650	V
Surge peak reverse voltage	V_{RSM}		650	V
Maximum DC forward current	I_F	T_C = 156°C	4	A
Non-repetitive forward surge current sine halfwave	I_{FSM}	T_C = 25°C, t_p = 10ms	30	A
		T_C = 110°C, t_p =10ms	24	
Repetitive forward surge current sine halfwave, D=0.1	I_{FRM}	T_C = 25°C, t_p = 10ms	21.5	A
		T_C = 110°C, t_p =10ms	12.4	
Non-repetitive peak forward current	$I_{F,max}$	T_C = 25°C, t_p =10µs	235	A
		T_C = 110°C, t_p =10µs	212	
Non-repetitive avalanche energy	E_{AS}	T_j = 25°C, L = 5mH, Ipk=3.55A, V_{DD}=100V	33	mJ
Power dissipation	P_{Tot}	T_C = 25°C	71	W
		T_C = 156°C	9	
Maximum junction temperature	$T_{J,max}$		175	°C
Operating and storage temperature	T_J, T_{STG}		-55 to 175	°C
Soldering temperatures, wavesoldering only allowed at leads	T_{sold}	1.6mm from case for 10s	260	°C

Electrical Characteristics

T_J = +25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Value			Units
			Min	Typ	Max	
Forward voltage	V_F	I_F = 4A, T_J = 25°C	-	1.5	1.7	V
		I_F = 4A, T_J =150°C	-	1.8	2.1	
		I_F = 4A, T_J =175°C	-	2	2.25	
Reverse current	I_R	V_R=650V, T_j=25°C	-	10	170	µA
		V_R=650V, T_J=175°C	-	20	550	
Total capacitive charge (1)	Q_C	V_R=400V		9.3		nC
Total capacitance	C	V_R=1V, f=1MHz		125		pF
		V_R=300V, f=1MHz		16		
		V_R=600V, f=1MHz		13		
Capacitance stored energy	E_C	V_R=400V		1.3		µJ

(1) See Figure 8, Q_c is independent on T_j, di_F/dt, and I_F as shown in the application note USCi_AN0011.

Thermal characteristics

Parameter	symbol	Test Conditions	Value			Units
			Min	Typ	Max	
Thermal resistance	$R_{\theta JC}$			1.57	2.1	°C/W

Typical Performance

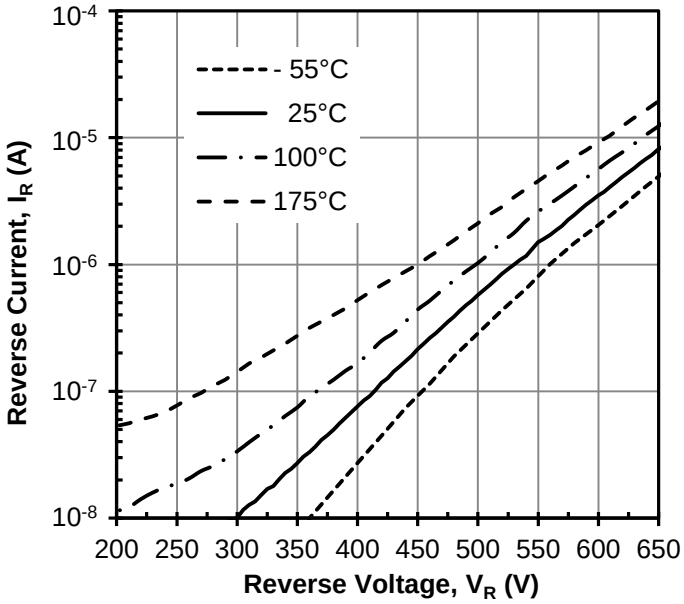


Figure 1 Typical reverse characteristics

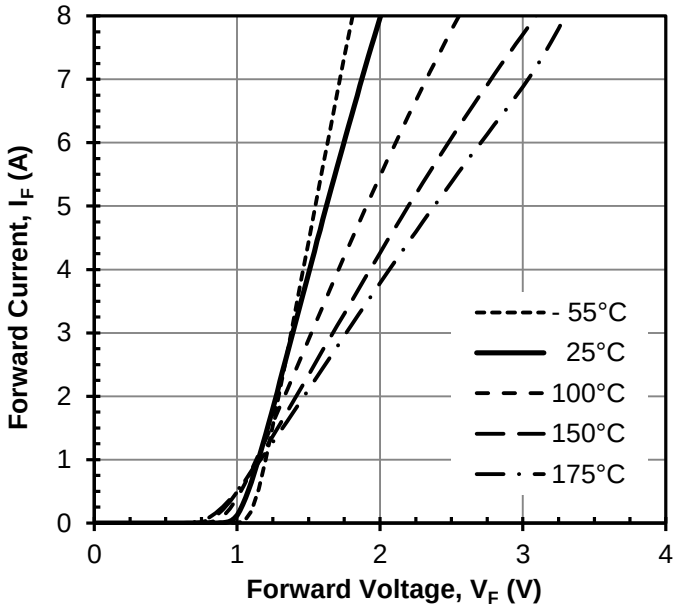


Figure 2 Typical forward characteristics

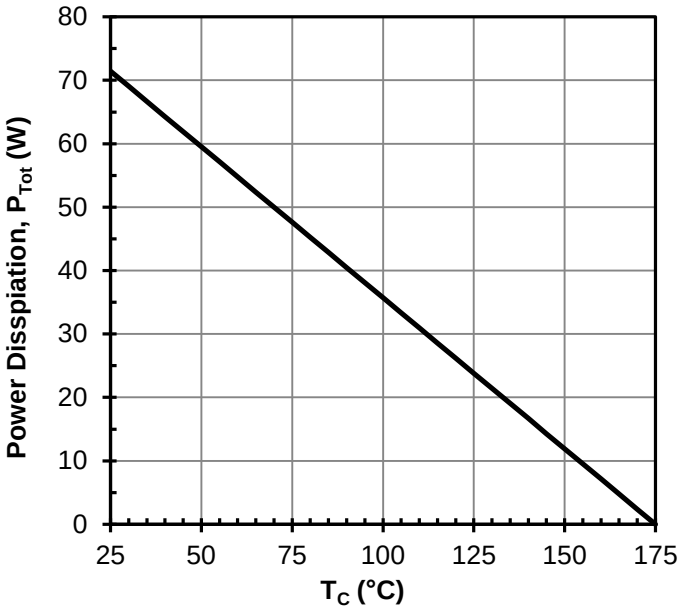


Figure 3 Power dissipation

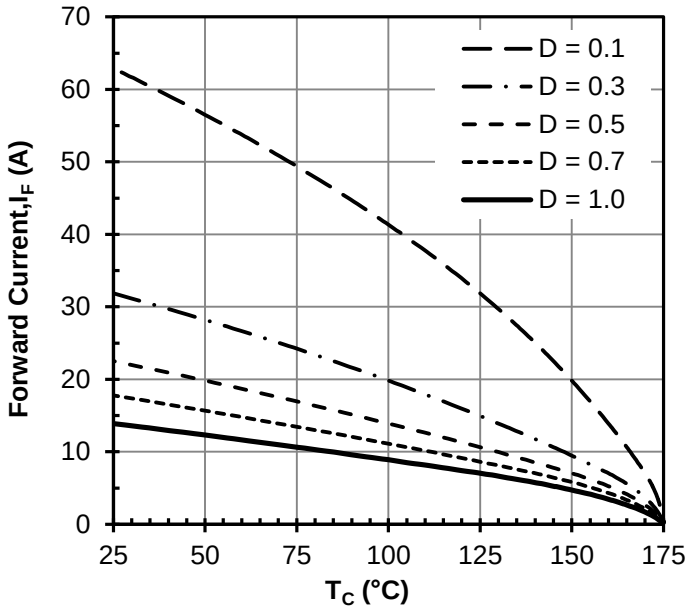


Figure 4 Diode forward current

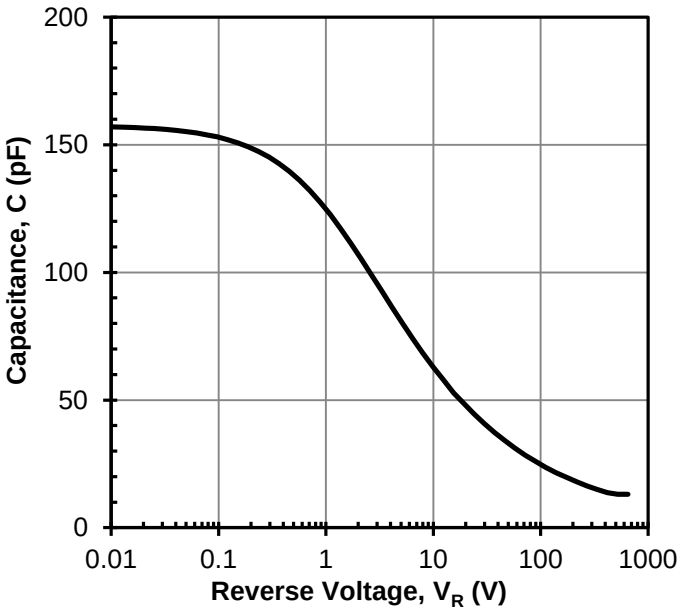


Figure 5 Capacitance vs. reverse voltage

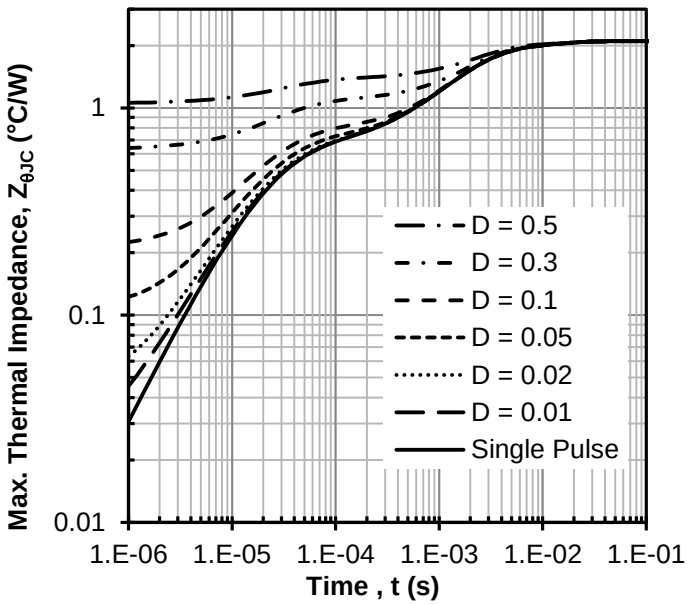


Figure 6 Maximum transient thermal impedance

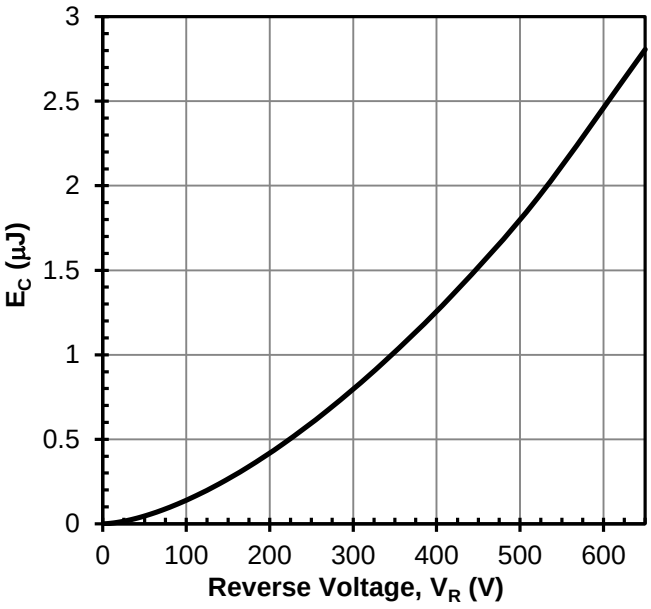


Figure 7 Typical capacitance stored energy vs. reverse voltage

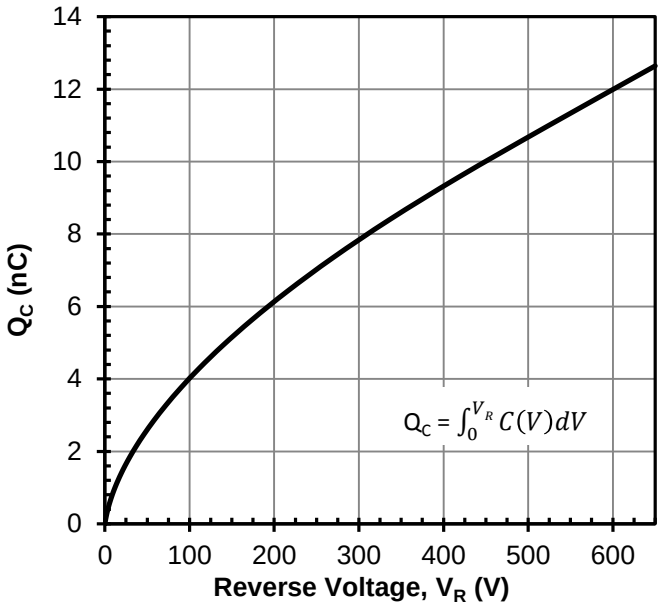


Figure 8 Typical capacitive charge vs. reverse voltage

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